



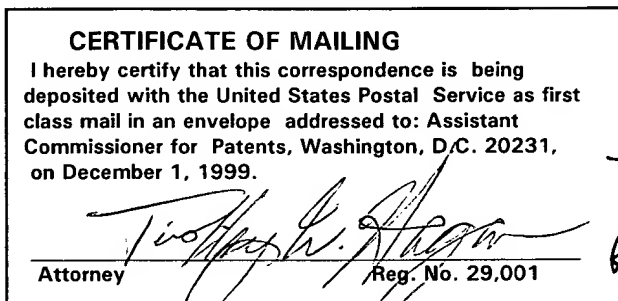
282823

THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of

Applicant : Howard Rhodes, Luan Tran ✓  
Serial No. : 09/008,531 ✓  
Filed : January 16, 1998 ✓  
Title : METHOD OF MAKING A SEMICONDUCTOR DEVICE HAVING  
IMPROVED CONTACTS TO A THIN CONDUCTIVE LAYER  
Examiner : K. Eaton  
Art Unit : 2823  
Docket : 94-0112.04 (MIO 012 V2)

Assistant Commissioner for  
Patents  
Washington, D.C. 20231



Sir:

REQUEST FOR RECONSIDERATION

This paper is being filed in response to the Office Action mailed September 30, 1999.

Reconsideration and reexamination are respectfully requested in light of the amendments and remarks below.

REMARKS

In the Office Action, the Examiner stated a requirement that applicants file a supplemental oath or declaration "to correct the deficiencies and/or inaccuracies (i.e., the addition of co-inventor Luan Tran) in the earlier filed declaration." Applicants respectfully disagree that a new declaration is required. MPEP §602.05(a) provides, in pertinent part:

**Oath or Declaration in Continuation and Divisional Applications**

A continuation or divisional application filed under 37 CFR 1.53(b) (other than a continuation-in-part (CIP)) may be filed with a copy of the oath or declaration from the prior nonprovisional application. See 37 CFR 1.63(d)(1)(iv).

A copy of an oath or declaration from a prior application may be submitted with a continuation or divisional application even if the oath or declaration identifies the application number of the prior application.

\* \* \* \*

RECEIVED  
DEC-7 1999  
TECHNICAL ROOM

#7  
Reg for

Recon.

J. McInnes

12/10/99